## NSN 5961-01-276-8944

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-276-8944 **Inclosure Material:** Plastic **Overall Length:** Between 0.575 inches and 0.620 inches **Terminal Length:** Between 0.500 inches and 0.562 inches **Overall Height:** Between 0.160 inches and 0.190 inches **Overall Width:** Between 0.380 inches and 0.405 inches **Function For Which Designed:** Amplifier and switching **End Application:** 6625-01-212-3679 generator, sweep **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method: Terminal** Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter voltage/static/base open and 100.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 2.00 amperes source cutoff current and 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 2500.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

## **NSN 5961-01-276-8944** Transistor - Page 2 of 2



Fiig:

A110a0